

N-Channel Power MOSFET

30V, 194A, 1.8mΩ

FEATURES

- Low $R_{DS(ON)}$ to minimize conductive losses
- Low gate charge for fast power switching
- 100% UIS and R_g tested
- 175°C Operating Junction Temperature
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS

PARAMETER	VALUE	UNIT
V_{DS}	30	V
$R_{DS(on)}$ (max)	1.8	mΩ
	2.8	
Q_g	62	nC

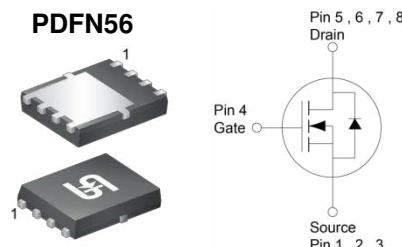
APPLICATIONS

- DC-DC Converter
- Battery Management
- Load Switch
- Motor Drive



RoHS
COMPLIANT

HALOGEN
FREE



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ^(Note 1)	I_D	194	A
$T_C = 25^\circ\text{C}$		29	A
Pulsed Drain Current	I_{DM}	776	A
Single Pulse Avalanche Current ^(Note 2)	I_{AS}	52	A
Single Pulse Avalanche Energy ^(Note 2)	E_{AS}	406	mJ
Total Power Dissipation	P_D	136	W
$T_C = 125^\circ\text{C}$		45	W
Total Power Dissipation	P_D	3.1	W
$T_A = 125^\circ\text{C}$		1	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +175	°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	MAXIMUM	UNIT
Junction to Case Thermal Resistance	R_{EJC}	1.1	°C/W
Junction to Ambient Thermal Resistance	R_{EJA}	48	°C/W

Thermal Performance Note: R_{EJA} is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. R_{EJC} is guaranteed by design while R_{ECA} is determined by the user's board design. The R_{EJA} limit presented here is based on mounting on a 1 in² pad of 2 oz copper.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	BV_{DSS}	30	--	--	V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	$V_{GS(\text{TH})}$	1	1.8	2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Drain-Source Leakage Current	$V_{GS} = 0\text{V}, V_{DS} = 30\text{V}$	I_{DSS}	--	--	1	μA
	$V_{GS} = 0\text{V}, V_{DS} = 30\text{V}$ $T_J = 125^\circ\text{C}$		--	--	100	
Drain-Source On-State Resistance (Note 3)	$V_{GS} = 10\text{V}, I_D = 29\text{A}$	$R_{DS(\text{on})}$	--	1.4	1.8	$\text{m}\Omega$
	$V_{GS} = 4.5\text{V}, I_D = 24\text{A}$		--	2.1	2.8	
Forward Transconductance (Note 3)	$V_{DS} = 10\text{V}, I_D = 29\text{A}$	g_{fs}	--	70	--	S
Dynamic (Note 4)						
Total Gate Charge	$V_{GS} = 10\text{V}, V_{DS} = 15\text{V}, I_D = 29\text{A}$	Q_g	--	120	--	nC
Total Gate Charge	$V_{GS} = 4.5\text{V}, V_{DS} = 15\text{V}, I_D = 24\text{A}$	Q_g	--	62	--	
Gate-Source Charge		Q_{gs}	--	21	--	
Gate-Drain Charge		Q_{gd}	--	28	--	
Input Capacitance	$V_{GS} = 0\text{V}, V_{DS} = 15\text{V}, f = 1.0\text{MHz}$	C_{iss}	--	7252	--	pF
Output Capacitance		C_{oss}	--	1056	--	
Reverse Transfer Capacitance		C_{rss}	--	673	--	
Gate Resistance	$f = 1.0\text{MHz}$	R_g	0.5	1.8	3.6	Ω
Switching (Note 4)						
Turn-On Delay Time	$V_{GS} = 10\text{V}, V_{DS} = 15\text{V}, I_D = 29\text{A}, R_G = 2\Omega$	$t_{d(on)}$	--	9	--	ns
Turn-On Rise Time		t_r	--	50	--	
Turn-Off Delay Time		$t_{d(off)}$	--	80	--	
Turn-Off Fall Time		t_f	--	45	--	
Source-Drain Diode						
Forward Voltage (Note 3)	$V_{GS} = 0\text{V}, I_S = 29\text{A}$	V_{SD}	--	--	1	V
Reverse Recovery Time	$I_S = 29\text{A}, dI/dt = 100\text{A}/\mu\text{s}$	t_{rr}	--	48	--	ns
Reverse Recovery Charge		Q_{rr}	--	50	--	nC

Notes:

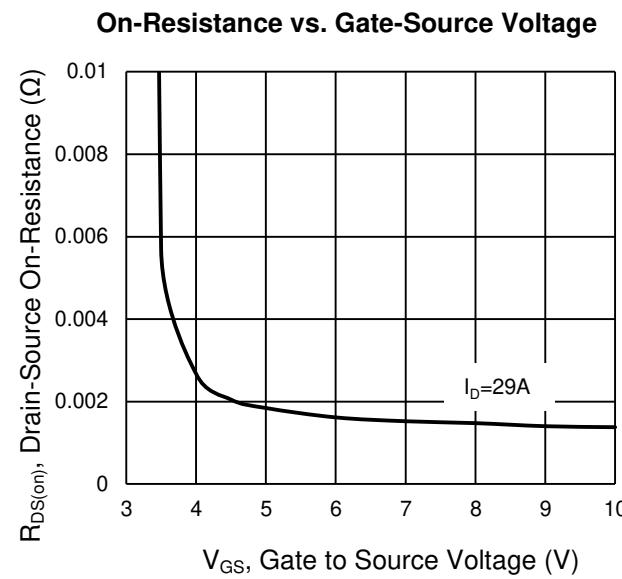
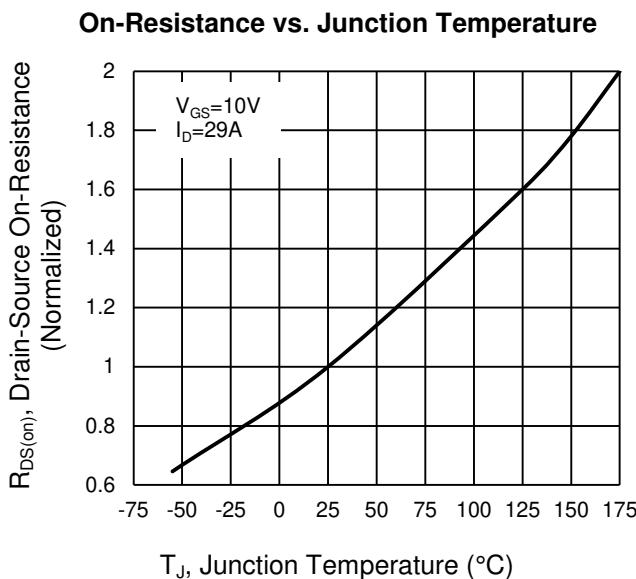
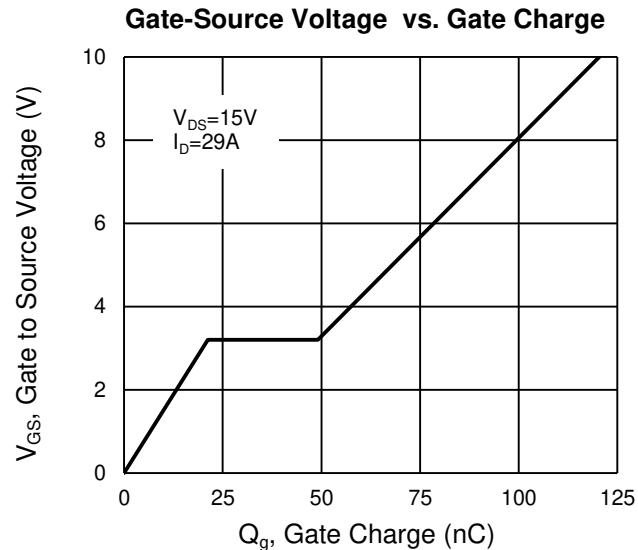
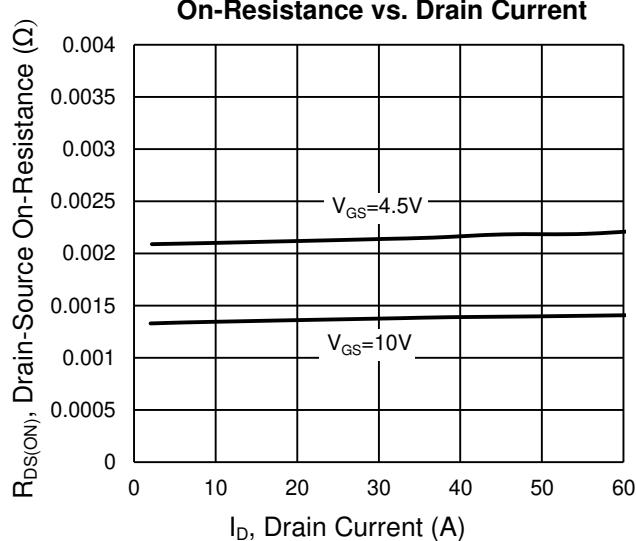
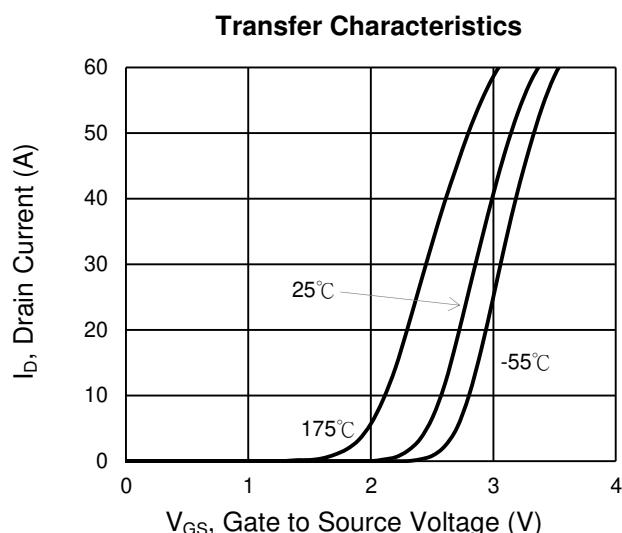
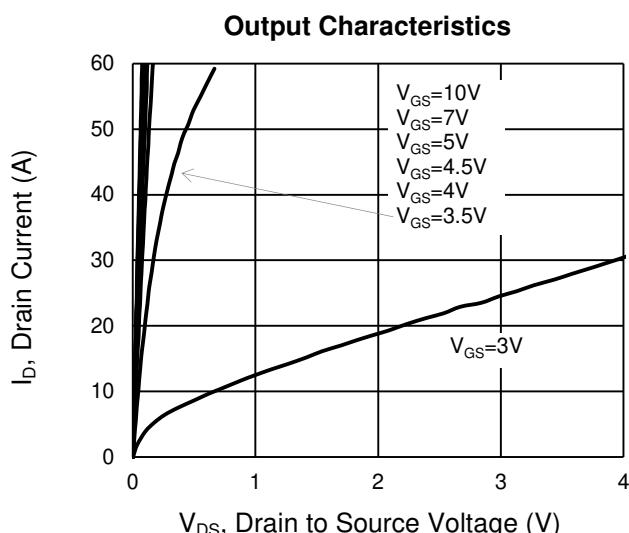
1. Silicon limited current only.
2. $L = 0.3\text{mH}, V_{GS} = 10\text{V}, V_{DD} = 25\text{V}, R_G = 25\Omega, I_{AS} = 52\text{A}$, Starting $T_J = 25^\circ\text{C}$
3. Pulse test: Pulse Width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
4. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSM018NB03CR RLG	PDFN56	2,500pcs / 13" Reel

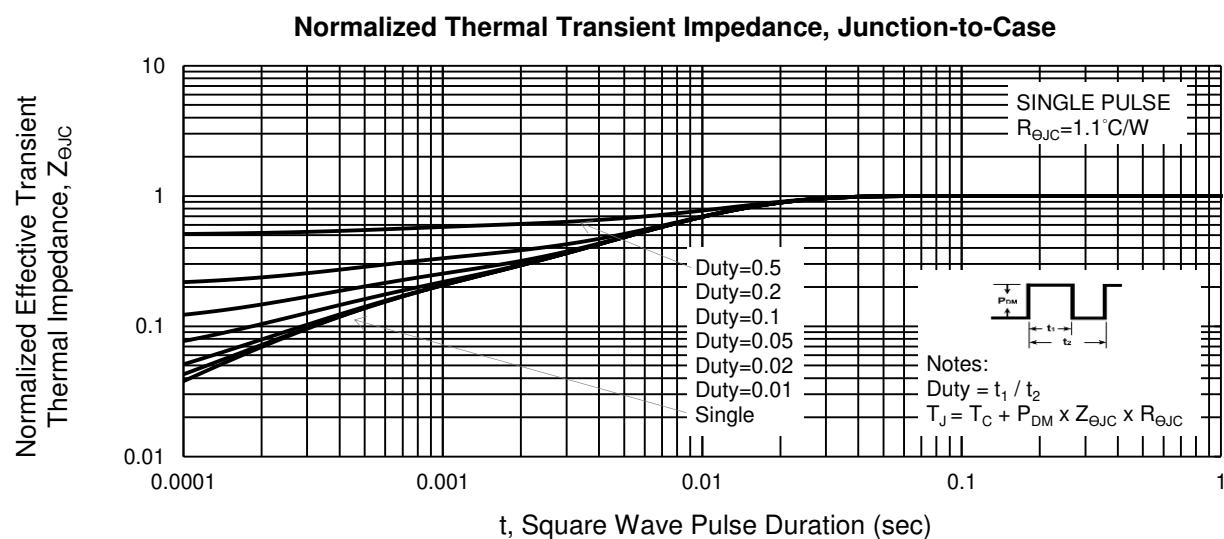
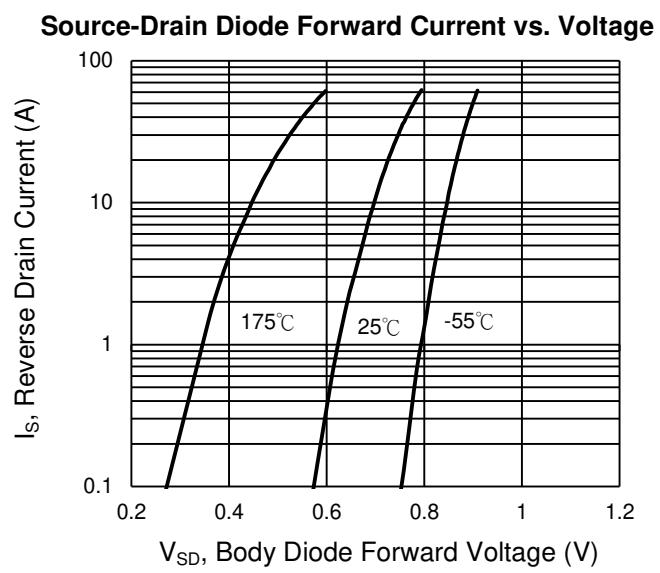
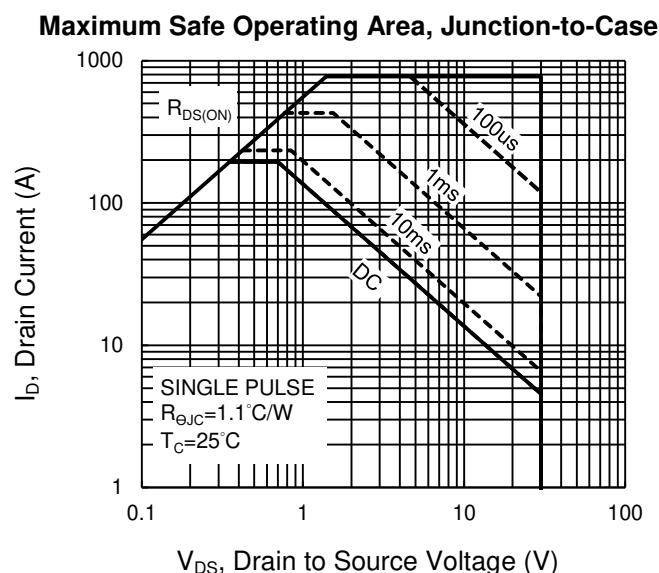
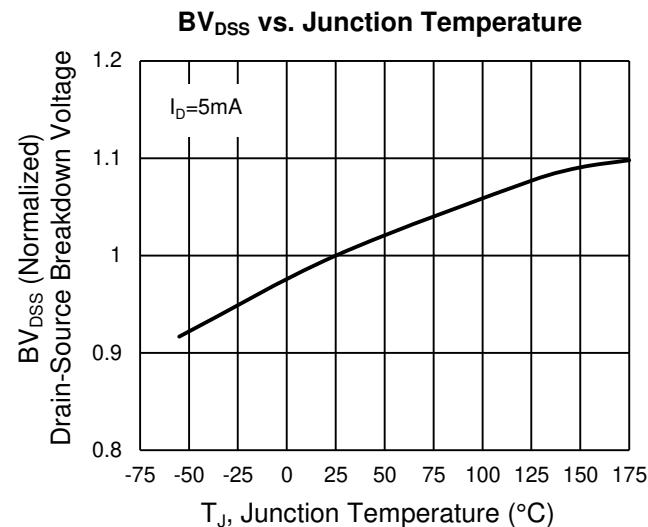
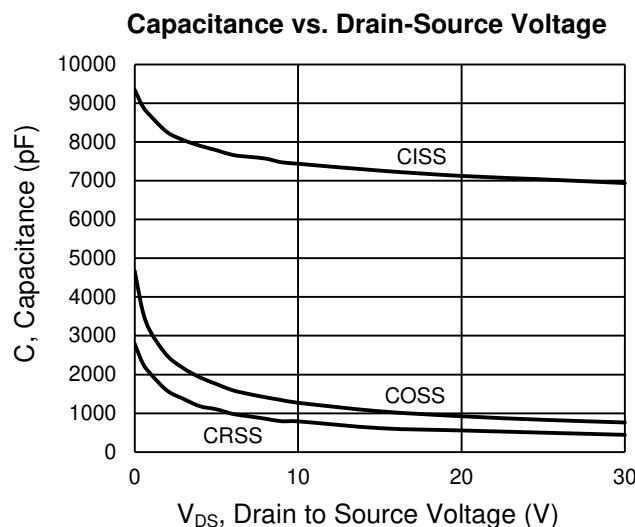
CHARACTERISTICS CURVES

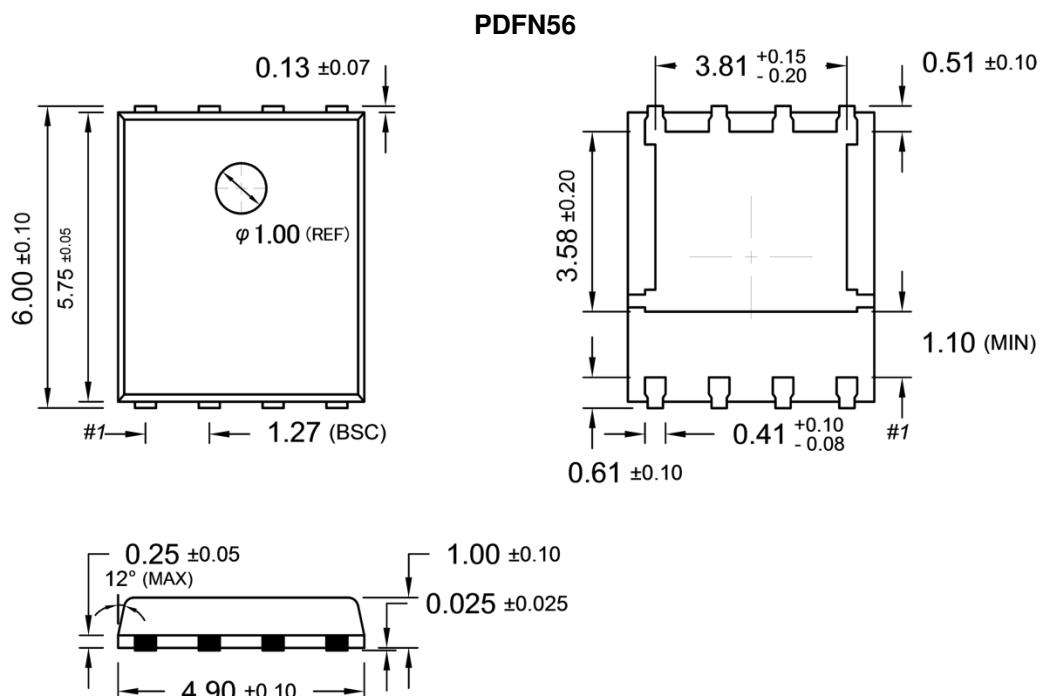
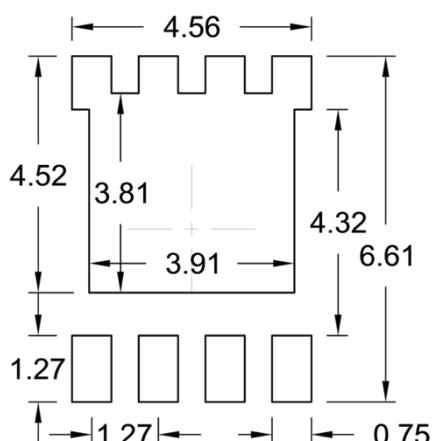
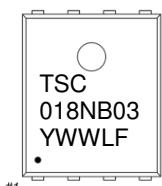
($T_A = 25^\circ\text{C}$ unless otherwise noted)



CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SUGGESTED PAD LAYOUT (Unit: Millimeters)

MARKING DIAGRAM


- Y** = Year Code
- WW** = Week Code (01~52)
- L** = Lot Code (1~9,A~Z)
- F** = Factory Code

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